

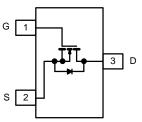
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2SK3546J-VB Datasheet

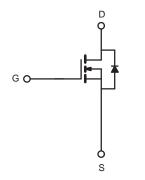
N-Channel 60V (D-S) MOSFET

| PRODUCT SUMMARY | | | | |
|---------------------|-------------------------------|---------------------|--|--|
| V _{DS} (V) | R _{DS(on)} (Ω) | I _D (mA) | | |
| 60 | 1.2 at V _{GS} = 10 V | 330 | | |









FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- Low On-Resistance: 2 Ω
- Low Threshold: 2 V (typ.)
- Low Input Capacitance: 25 pF
- Fast Switching Speed: 25 ns
- Low Input and Output Leakage
- Trench Power MOSFET
- Compliant to RoHS Directive 2002/95/EC

BENEFITS

- Low Offset Voltage
- Low-Voltage Operation
- Easily Driven Without Buffer
- High-Speed Circuits
- Low Error Voltage

APPLICATIONS

- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- Battery Operated Systems
- Solid-State Relays

| ABSOLUTE MAXIMUM RATINGS $T_A = 25 \text{ °C}$, unless otherwise noted | | | | | |
|--|-------------------------|----------------------------------|-------------|------|--|
| Parameter | | Symbol | Limit | Unit | |
| Drain-Source Voltage | | V _{DS} | 60 | V | |
| Gate-Source Voltage | | V _{GS} | ± 20 | v | |
| Continuous Drain Current (T ₁ = 150 °C) ^b | T _A = 25 °C | . I _D | 330 | mA | |
| Continuous Drain Current $(T_J = 150^{\circ}C)^{\circ}$ | T _A = 100 °C | | 290 | | |
| Pulsed Drain Current ^a | | I _{DM} | 800 | | |
| Denor Director di sub | T _A = 25 °C | PD | 0.35 | 10/ | |
| Power Dissipation ^b | T _A = 100 °C | ۲D | 0.14 | W | |
| Maximum Junction-to-Ambient ^b | | R _{thJA} | 350 | °C/W | |
| Operating Junction and Storage Temperature Range | | T _{J,} T _{stg} | - 55 to 150 | °C | |

Notes:

a. Pulse width limited by maximum junction temperature.

b. Surface Mounted on FR4 board.



| 9 | B | ® | Bs | sen | ni |
|---|------|-----|----|------|----|
| W | ww.V | /Bs | em | i.co | m |

| | | | Limits | | | | |
|---|---------------------|---|----------|---|------------------------|----|--|
| Parameter | Symbol | Test Conditions | Min. | Typ. ^a | Typ. ^a Max. | | |
| Static | | | • | • | • | | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0 V, I_D = 10 \mu A$ | 60 | | | v | |
| Gate-Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$ | 1 | | 2.5 | v | |
| | | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | | ± 10 | | |
| | | $V_{DS} = 0 V, V_{GS} = \pm 15 V$ | | | 1 | μA | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 10 V$ | | | ± 150 | nA | |
| | | $V_{DS} = 0 V, V_{GS} = \pm 10 V, T_{J} = 85 °C$ | | | ± 1000 | | |
| | | $V_{DS} = 0 V, V_{GS} = \pm 5 V$ | | | ± 100 | | |
| Zura Osta Malta en Dasia Osmaal | - | $V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$ | | | 1 | μA | |
| Zero Gate Voltage Drain Current | IDSS | V_{DS} = 60 V, V_{GS} = 0 V , T_{J} = 125 °C | | | 500 | | |
| On-State Drain Current ^a | I _{D(on)} | V _{GS} = 10 V, V _{DS} = 7.5 V 800 | | | | | |
| | | $V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}$ | 500 | | | mA | |
| | R _{DS(on)} | V _{GS} = 10 V, I _D = 500 mA | | 1.2 | | 0 | |
| Drain-Source On-Resistance ^a | | V _{GS} = 4.5 V, I _D = 200 mA 2 | | 2 | | Ω | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = 10 V, I _D = 200 mA 100 | | | | mS | |
| Diode Forward Voltage | V _{SD} | I _S = 200 mA, V _{GS} = 0 V | | | 1.3 | V | |
| Dynamic ^a | | | <u> </u> | I | <u>1</u> | | |
| Total Gate Charge | Qg | $V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}$ $I_D \cong 250 \text{ mA}$ | | 0.4 | 0.6 | nC | |
| Input Capacitance | C _{iss} | | | 30 | | | |
| Output Capacitance | C _{oss} | $V_{\rm DS} = 25 \text{ V}, V_{\rm GS} = 0 \text{ V}$ | | 6 | | pF | |
| Reverse Transfer Capacitance | C _{rss} | f = 1 MHz | | 2.5 | | 1 | |
| Switching ^{a, b, c} | | | | | | | |
| Turn-On Time | t _{d(on)} | V_{DD} = 30 V, R_{L} = 150 Ω | | | 25 | | |
| Turn-Off Time | t _{d(off)} | $I_D \cong 200 \text{ mA}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{G}} = 10 \Omega$ | | t i i i i i i i i i i i i i i i i i i i | 35 | ns | |

Notes:

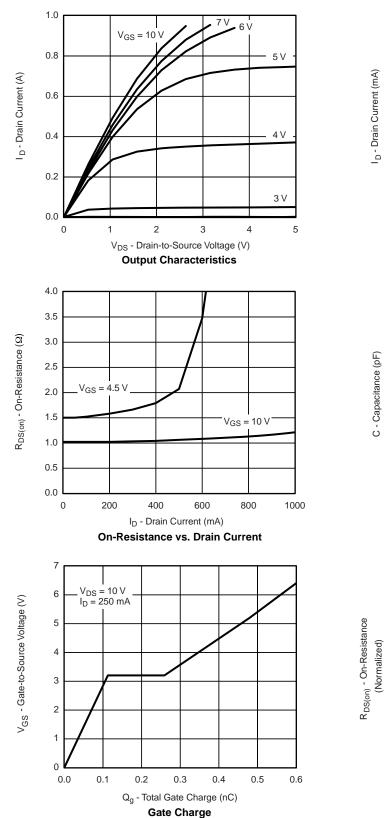
a. For DESIGN AID ONLY, not subject to production testing.

b. Pulse test: PW \leq 300 μs duty cycle \leq 2 %.

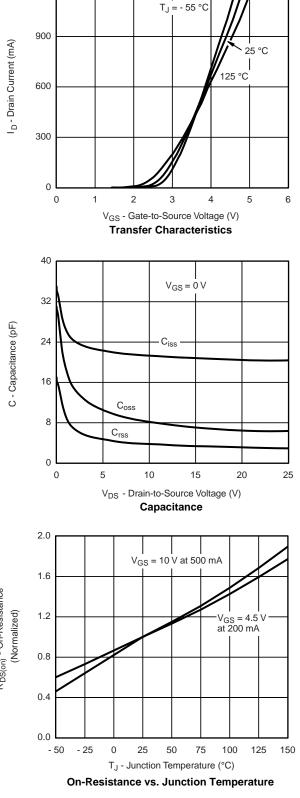
c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





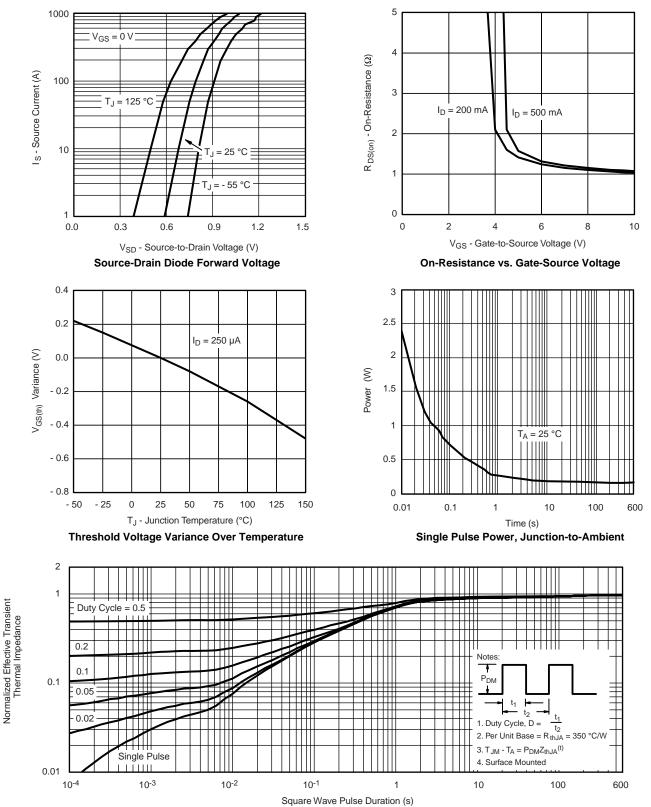
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



1200

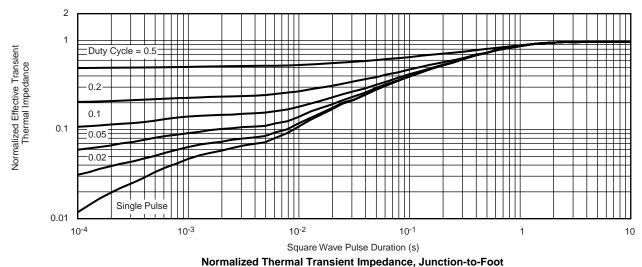


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted









THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)

Note

• The characteristics shown in the two graphs

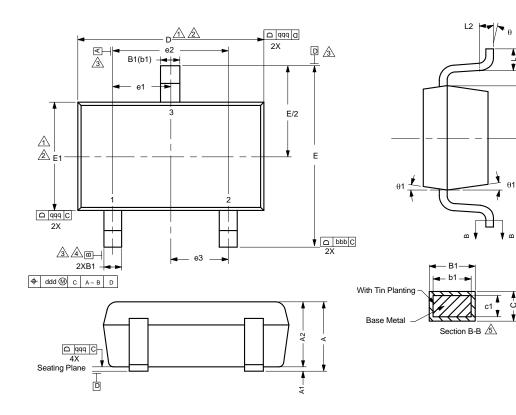
- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.



SC-75A: 3 Leads



Notes

Dimensions in millimeters will govern.

- Dimension D does not include mold flash, protrusions or gate burrs. Mold flash protrusions or gate burrs shall not exceed 0.10 mm per end. Dimension E1 does not include Interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.10 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interelead flash, but including any mismatch between the top and bottom of the plastic body.

 $\underline{3}$ Datums A, B and D to be determined 0.10 mm from the lead tip.

4. Terminal positions are shown for reference only.

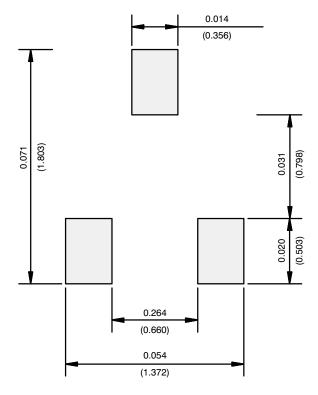
 $\frac{1}{2}$ These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

| DIMENSIONS | TOLERANCES | | |
|------------|------------|--|--|
| aaa | 0.10 | | |
| bbb | 0.10 | | |
| ccc | 0.10 | | |
| ddd | 0.10 | | |

| DIM. | n in the second s | | | |
|----------------|---|----------|------|------|
| DIM. | MIN. | NOM. | MAX. | NOTE |
| А | - | - | 0.80 | |
| A ₁ | 0.00 | - | 0.10 | |
| A ₂ | 0.65 | 0.70 | 0.80 | |
| B ₁ | 0.19 | - | 0.24 | 5 |
| b ₁ | 0.17 | - | 0.21 | |
| С | 0.13 | - | 0.15 | 5 |
| C ₁ | 0.10 | - | 0.12 | 5 |
| D | 1.48 | 1.575 | 1.68 | 1, 2 |
| E | 1.50 | 1.60 | 1.70 | |
| E1 | 0.66 | 0.76 | 0.86 | 1, 2 |
| e ₁ | | 0.50 BSC | | |
| e ₂ | | 1.00 BSC | | |
| e ₃ | | 0.50 BSC | | |
| L | 0.15 | 0.205 | 0.30 | |
| L ₁ | 0.40 ref. | | | |
| L ₂ | 0.15 BSC | | | |
| θ | 0° | - | 8° | |
| θ1 | 4° | - | 10° | |



RECOMMENDED MINIMUM PADS FOR SC-75A: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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